

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Abdalla Aly Naem et al.

Appln. No.: Divisional of 10/315,394

Filed: Herewith

For: METHOD OF FORMING A MOS
TRANSISTOR WITH A LAYER OF
SILICON GERMANIUM CARBON
(as amended)

Group Art Unit: Unknown

Examiner: Unknown

PRELIMINARY AMENDMENT

INTRODUCTORY COMMENTS

Mail Stop Patent Application
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

This is a Preliminary Amendment. Please amend the above-identified application as indicated on the following pages.